

Application Specific Discretes  $A.S.D.^{TM}$ 

### MAIN APPLICATIONS

Where EMI filtering in ESD sensitive equipment is required :

- Mobile phone : handsets and accessories
- RF communications

### DESCRIPTION

The EMIF01-5250SC5 is a highly integrated T-filter designed to suppress EMI / RFI noise on I/O ports of mobile phones or RF communication equipment.

This filter includes ESD protection circuitry which prevents device destruction when subjected to ESD discharges.

The comprehensive layout of the EMIF01-5250SC5 filter allows design flexibility on high density boards.

#### **FEATURES**

- T-filtering functions for 2 wires.
- ESD protection of 15 kV (air discharge) per IEC1000-4-2
- Breakdown voltage : V<sub>BR</sub> = 6 V min.
- Low leakage current < 1 μA.</p>

### **BENEFITS**

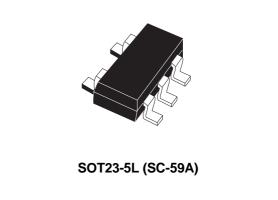
- EMI / RFI noise suppression.
- Enhanced ESD protection : IEC1000-4-2 level 4
- One of the smallest protection circuits available
- High flexibility in the design of high density boards

### COMPLIES WITH THE FOLLOWING STANDARDS

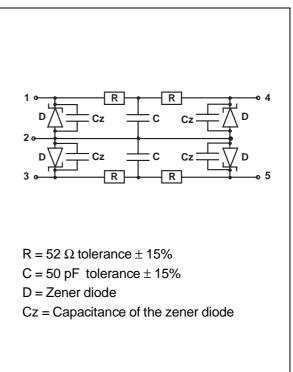
IEC 1000-4-2

15kV (air discharge) 8 kV (contact discharge)





### **FUNCTIONAL DIAGRAM**

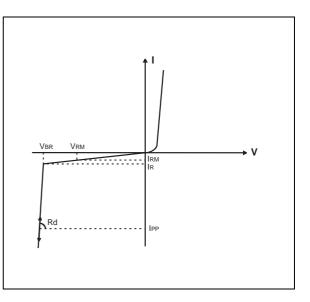


Symbol	Parameter and test conditions	Value	Unit
Vpp	ESD discharge IEC1000-4-2, air discharge	15	kV
	ESD discharge IEC1000-4-2, contact discharge	8	
Tj	Junction temperature	150	°C
T <sub>op</sub>	Operating temperature range	-30 to + 85	°C
T <sub>stg</sub>	Storage temperature range	-55 to +150	°C
TL	Lead temperature for soldering during 10s	260	°C

## ABSOLUTE MAXIMUM RATINGS (Tamb = 25 °C)

# ELECTRICAL CHARACTERISTICS of the ZENER DIODE (Tamb = 25 °C)

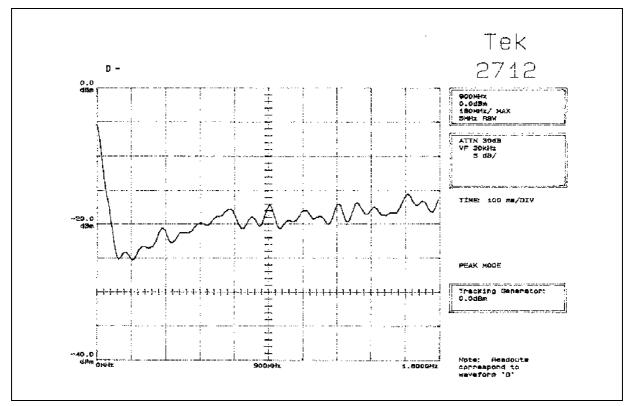
Symbol	Parameter
V <sub>BR</sub>	Breakdown voltage
I <sub>RM</sub>	Leakage current
Rd	Dynamic impedance
Cz	Zener capacitance
trr	Reverse recovery time

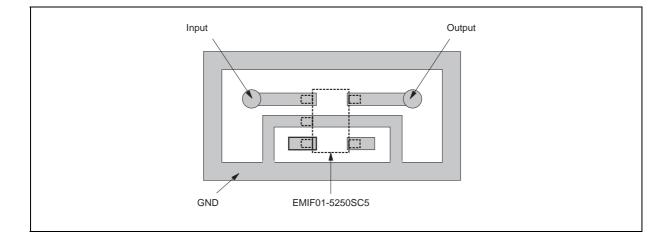


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Symbol	Test conditions	Min.	Тур.	Max.	Unit
Vbr	I <sub>R</sub> = 1 mA	6	7	8	V
I <sub>RM</sub>	V <sub>RM</sub> = 3V			1	μA
Rd	$I_{pp} = 10 \text{ A}, t_p = 2.5 \ \mu s$		0.55		Ω
Cz	0 V bias, $V_{RMS}$ = 30 mV, F = 1 MHz		90		pF
trr	I <sub>F</sub> = 10 mA, dI <sub>F</sub> /dt = 20 A/ $\mu$ s, R <sub>L</sub> = 100 $\Omega$ , Tj = 25 °C		40		ns

### **ATTENUATION BEHAVIOR**





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### **ESD BEHAVIOR**

### Fig 2 : ESD measurement conditions

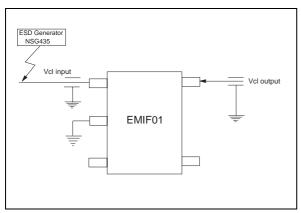
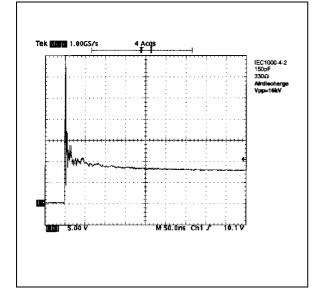
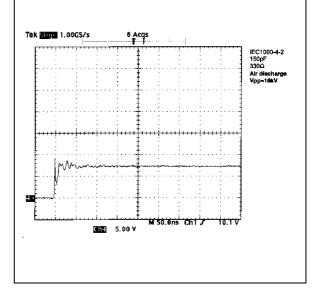


Fig 3 : ESD behavior on IEC1000-4-2 air discharge at input (typical value)

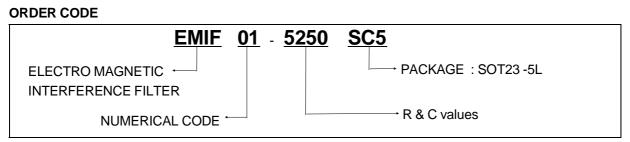


Figures 3 and 4 show the EMIF01-5250SC5 response to air and contact discharge conditions respectively at input and output pins. These figures indicate that the response is spontaneous and the output level is kept at safe operating voltages.

Fig 4 : ESD behavior on IEC1000-4-2 air discharge at output (typical value)



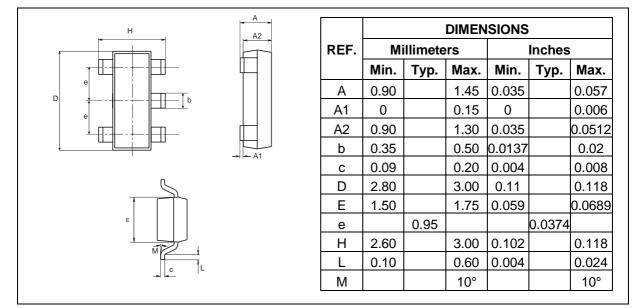
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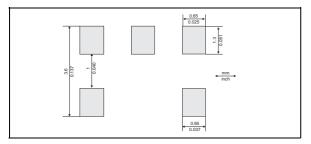
MARKING

Type & order code	Marking	Packaging	Base qty (pcs)
EMIF01-5250SC5	EMIF	tape & reel	3000

### PACKAGE MECHANICAL DATA



### **RECOMMENDED FOOT PRINT**



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